



# BFT25A

NPN 5 GHz wideband transistor

Rev. 5 — 12 September 2011

Product data sheet

## 1. Product profile

### 1.1 General description

The BFT25A is a silicon NPN transistor, primarily intended for use in RF low power amplifiers, such as pocket telephones and paging systems with signal frequencies up to 2 GHz.

The transistor is encapsulated in a 3-pin plastic SOT23 envelope.

### 1.2 Features and benefits

- Low current consumption (100  $\mu$ A to 1 mA)
- Low noise figure
- Gold metallization ensures excellent reliability.

### 1.3 Quick reference data

Table 1. Quick reference data

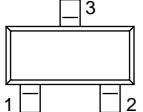
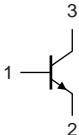
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	-	8	V
$V_{CEO}$	collector-emitter voltage	open base	-	-	5	V
$I_C$	DC collector current		-	-	6.5	mA
$P_{tot}$	total power dissipation	up to $T_s = 165$ °C	[1]	-	32	mW
$h_{FE}$	DC current gain	$I_C = 0.5$ mA; $V_{CE} = 1$ V	50	80	200	
$f_T$	transition frequency	$I_C = 1$ mA; $V_{CE} = 1$ V; $T_{amb} = 25$ °C; $f = 500$ MHz	3.5	5	-	GHz
$G_{UM}$	maximum unilateral power gain	$I_C = 0.5$ mA; $V_{CE} = 1$ V; $T_{amb} = 25$ °C; $f = 1$ GHz	-	15	-	dB
$F$	noise figure	$\Gamma = \Gamma_{opt}$ ; $I_C = 0.5$ mA; $V_{CE} = 1$ V; $T_{amb} = 25$ °C; $f = 1$ GHz	-	1.8	-	dB
		$\Gamma = \Gamma_{opt}$ ; $I_C = 1$ mA; $V_{CE} = 1$ V; $T_{amb} = 25$ °C; $f = 1$ GHz	-	2	-	dB

[1]  $T_s$  is the temperature at the soldering point of the collector tab.



## 2. Pinning information

Table 2. Discrete pinning

Pin	Description	Simplified outline	Symbol
<b>Code: V10</b>			
1	base		
2	emitter		
3	collector		 sym021

## 3. Ordering information

Table 3. Ordering information

Type number	Package		Version
	Name	Description	
BFT25A	-	plastic surface mounted package; 3 leads	SOT23

## 4. Marking

Table 4. Marking

Type number	Marking code <sup>[1]</sup>
BFT25A	34*

[1] \* = p : Made in Hong Kong.

\* = t : Made in Malaysia.

\* = W : Made in China.

## 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	8	V
$V_{CEO}$	collector-emitter voltage	open base	-	5	V
$V_{EBO}$	emitter-base voltage	open collector	-	2	V
$I_C$	DC collector current		-	6.5	mA
$P_{tot}$	total power dissipation	up to $T_s = 165^\circ\text{C}$	[1]	-	mW
$T_{stg}$	storage temperature		-65	+150	°C
$T_j$	junction temperature		-	175	°C

[1]  $T_s$  is the temperature at the soldering point of the collector tab.

## 6. Thermal characteristics

**Table 6. Thermal characteristics**

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-s)}$	from junction to soldering point		[1] 260	K/W

[1]  $T_s$  is the temperature at the soldering point of the collector tab.

## 7. Characteristics

**Table 7. Characteristics**

$T_j = 25^\circ\text{C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$I_{CBO}$	collector cut-off current	$I_E = 0 \text{ A}; V_{CB} = 5 \text{ V}$	-	-	50	nA
$h_{FE}$	DC current gain	$I_C = 0.5 \text{ mA}; V_{CE} = 1 \text{ V}$	50	80	200	
$f_T$	transition frequency	$I_C = 1 \text{ mA}; V_{CE} = 1 \text{ V}; T_{amb} = 25^\circ\text{C}; f = 500 \text{ MHz}$	3.5	5	-	GHz
$C_{re}$	feedback capacitance	$I_C = i_c = 0 \text{ A}; V_{CB} = 1 \text{ V}; f = 1 \text{ MHz}$	-	0.3	0.45	pF
$G_{UM}$	maximum unilateral power gain	$I_C = 0.5 \text{ mA}; V_{CE} = 1 \text{ V}; T_{amb} = 25^\circ\text{C}; f = 1 \text{ GHz}$	[1] -	15	-	dB
$F$	noise figure	$\Gamma = \Gamma_{opt}; I_C = 0.5 \text{ mA}; V_{CE} = 1 \text{ V}; T_{amb} = 25^\circ\text{C}; f = 1 \text{ GHz}$	-	1.8	-	dB
		$\Gamma = \Gamma_{opt}; I_C = 1 \text{ mA}; V_{CE} = 1 \text{ V}; T_{amb} = 25^\circ\text{C}; f = 1 \text{ GHz}$	-	2	-	dB

[1]  $G_{UM}$  is the maximum unilateral power gain, assuming  $S_{12}$  is zero and

$$G_{UM} = 10 \log \frac{|S_{21}|^2}{(1 - |S_{11}|^2)(1 - |S_{22}|^2)} \text{ dB}$$

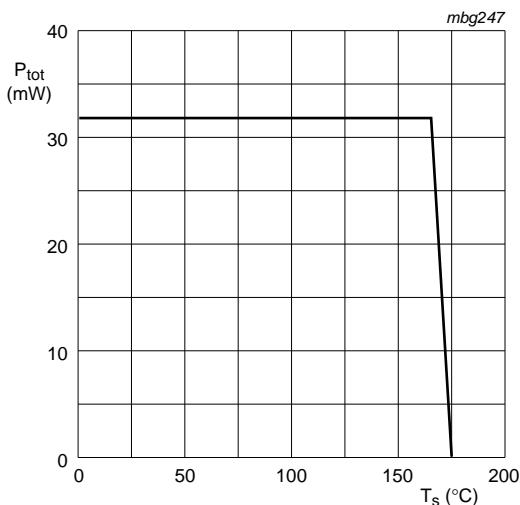


Fig 1. Power derating curve.

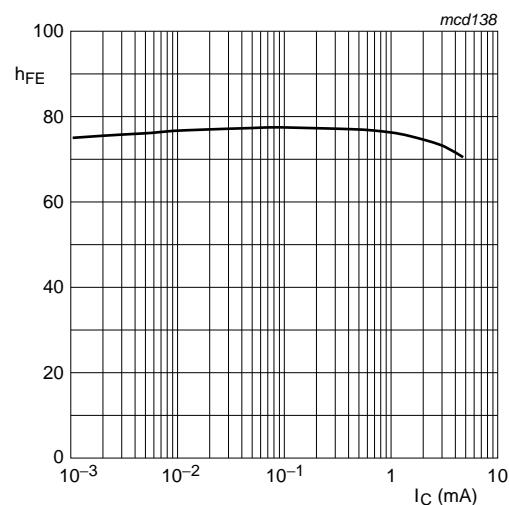
 $V_{CE} = 1$  V.

Fig 2. DC current gain as a function of collector current.

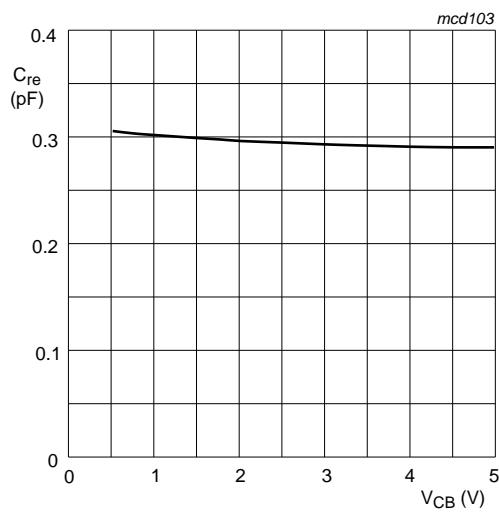
 $I_C = i_c = 0$  A;  $f = 1$  MHz.

Fig 3. Feedback capacitance as a function of collector-base voltage.

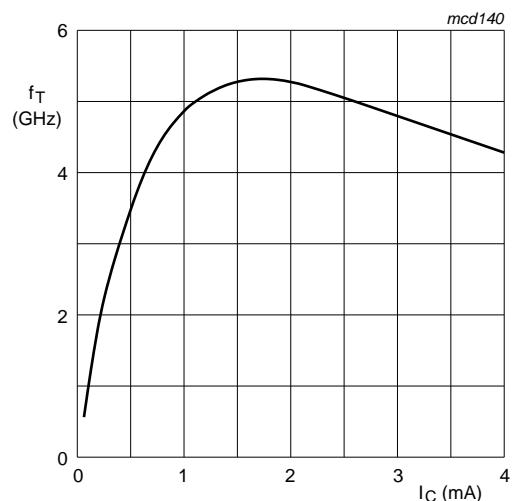
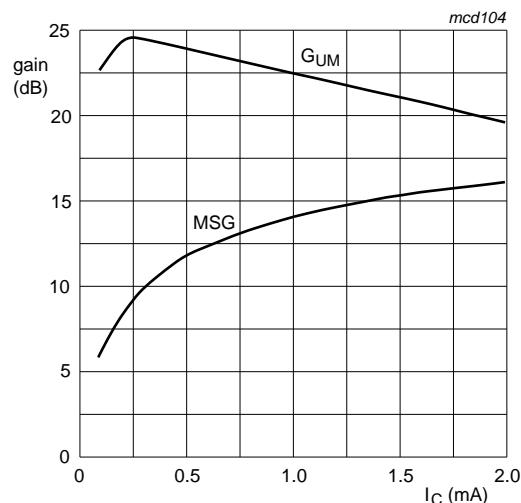
 $V_{CE} = 1$  V;  $T_{amb} = 25$  °C;  $f = 500$  MHz.

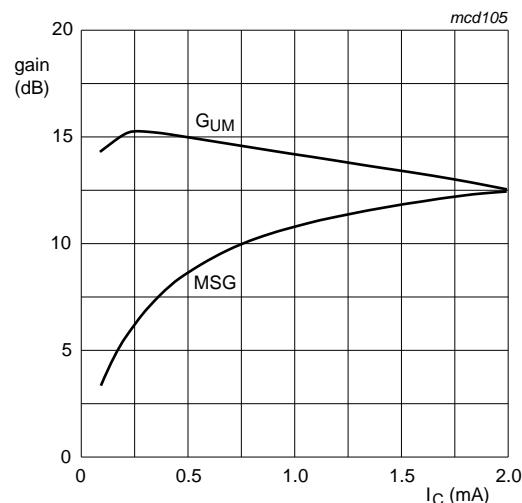
Fig 4. Transition frequency as a function of collector current.

[Figure 5](#), [Figure 6](#), [Figure 7](#) and [Figure 8](#),  $G_{UM}$  = maximum unilateral power gain; MSG = maximum stable gain.



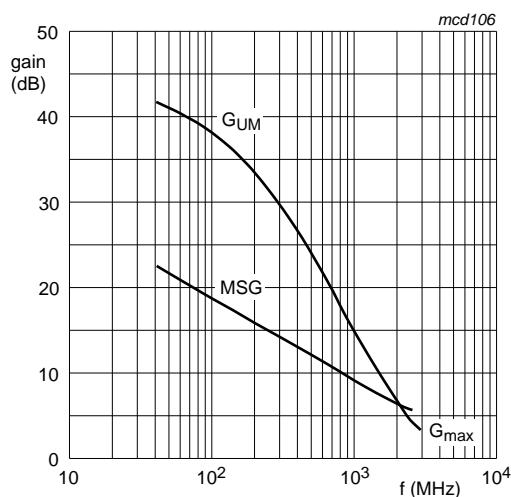
$V_{CE} = 1$  V;  $f = 500$  MHz.

**Fig 5. Gain as a function of collector current.**



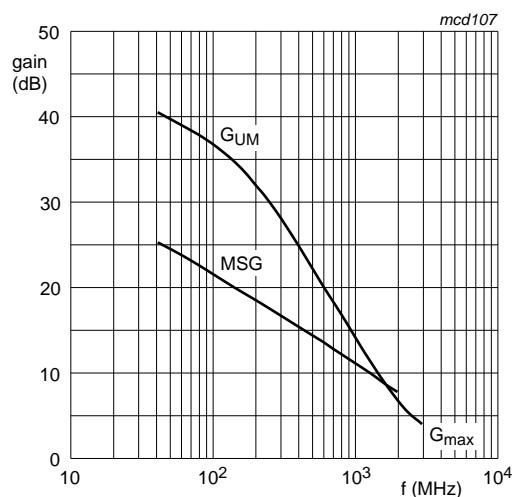
$V_{CE} = 1$  V;  $f = 1$  GHz.

**Fig 6. Gain as a function of collector current.**



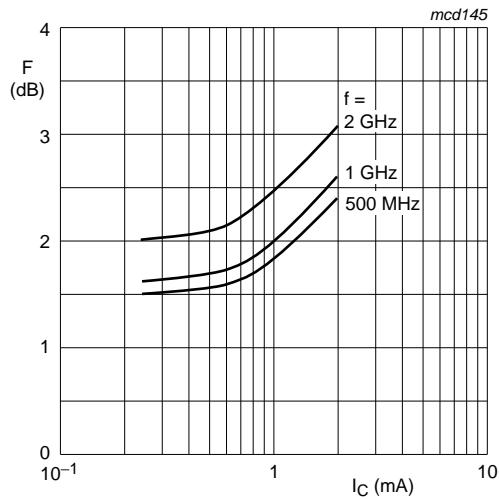
$V_{CE} = 1$  V;  $I_C = 0.5$  mA.

**Fig 7. Gain as a function of frequency.**



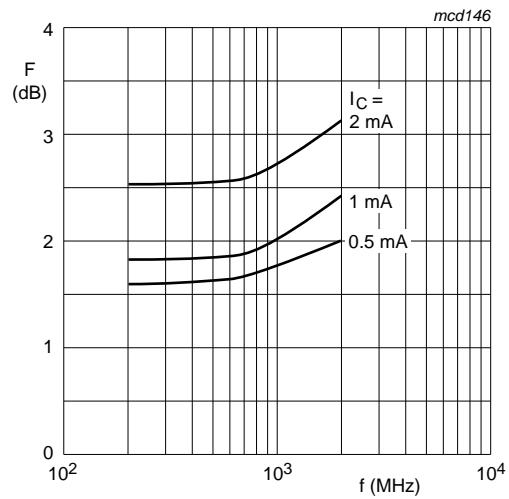
$V_{CE} = 1$  V;  $I_C = 1$  mA.

**Fig 8. Gain as a function of frequency.**



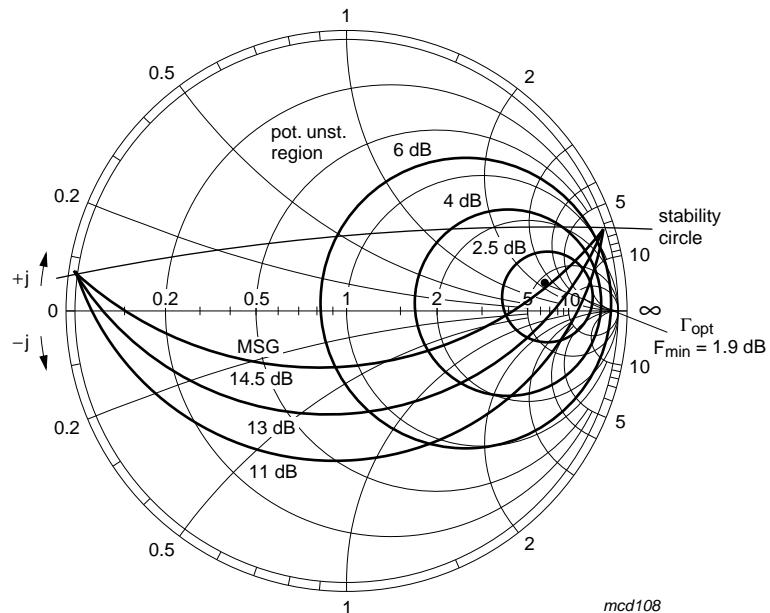
$V_{CE} = 1$  V.

**Fig 9. Minimum noise figure as a function of collector current.**



$V_{CE} = 1$  V.

**Fig 10. Minimum noise figure as a function of frequency.**



See Table 8;

$Z_0 = 50 \Omega$ .

Average gain parameter: MSG = 14.5 dB.

**Fig 11. Noise circle figure.**

Table 8. Noise parameters

$f$ (MHz)	$V_{CE}$ (V)	$I_C$ (mA)	$F_{min}$ (dB)	$\Gamma_{opt}$ (mag)	$\Gamma_{opt}$ (ang)	$R_n/50$
500	1	1	1.9	0.79	4	2.5

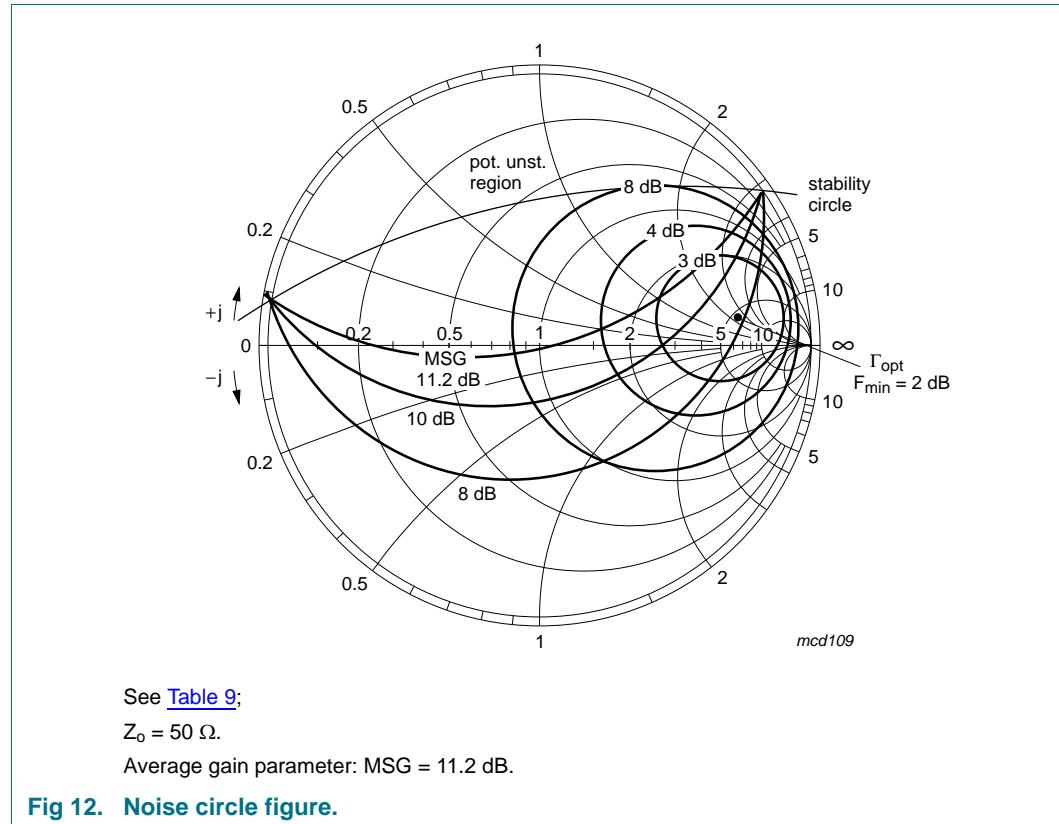
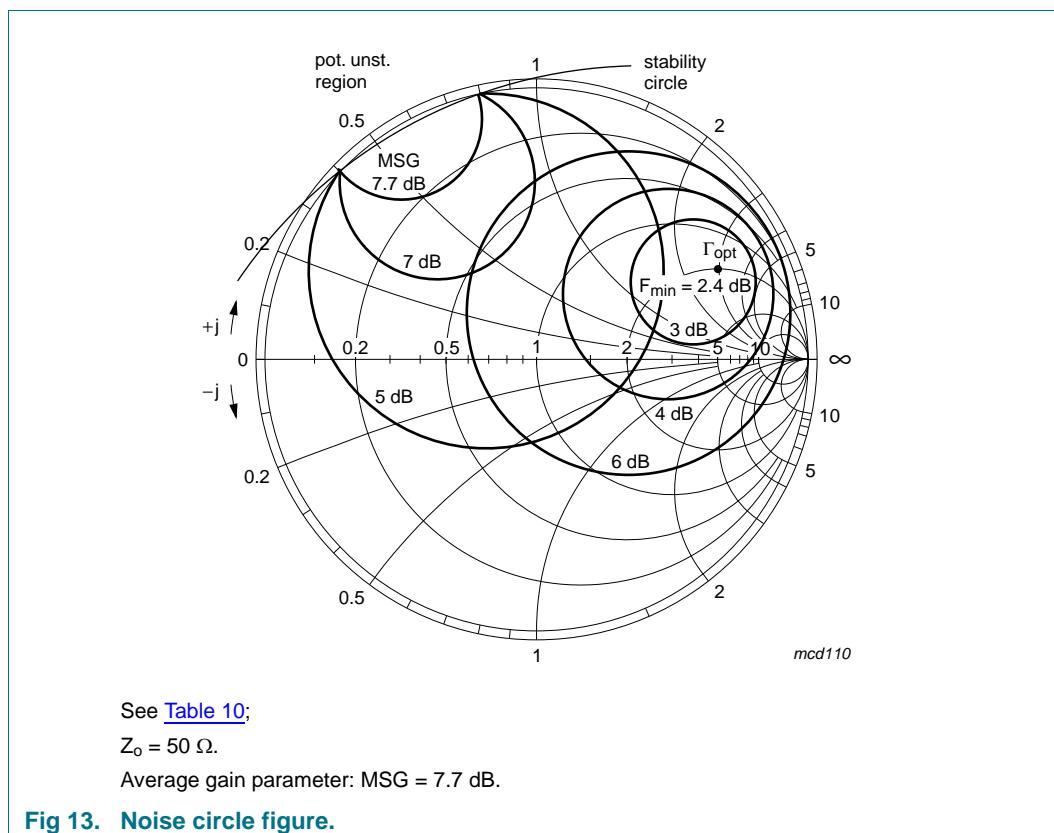
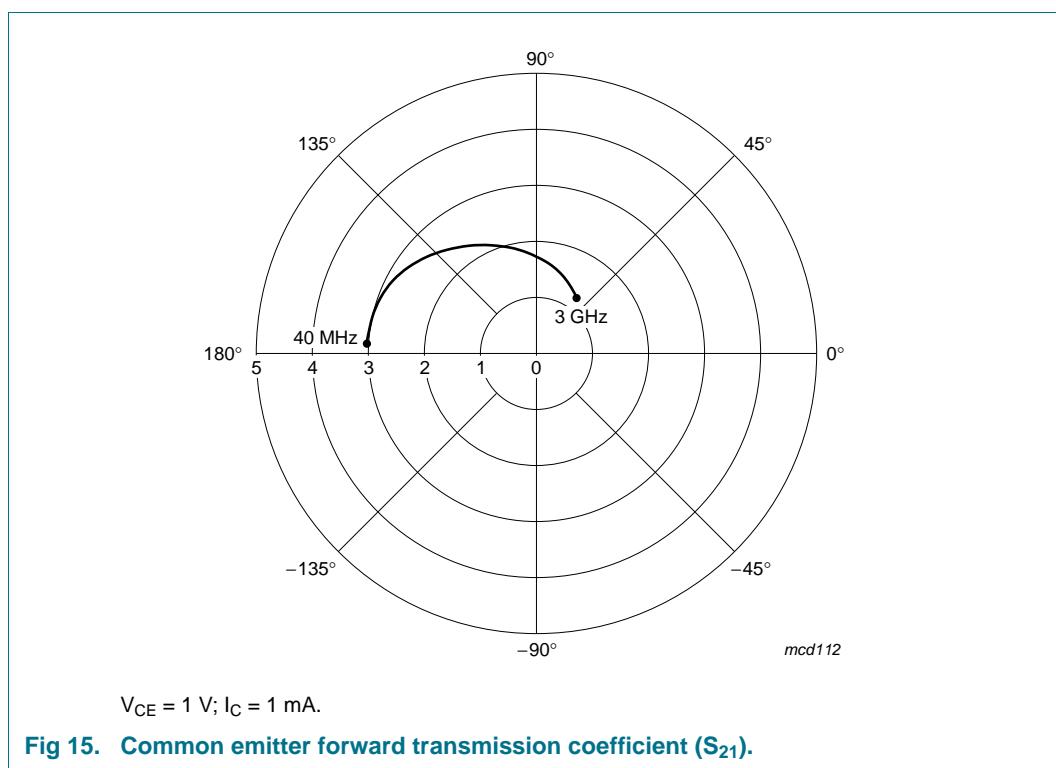
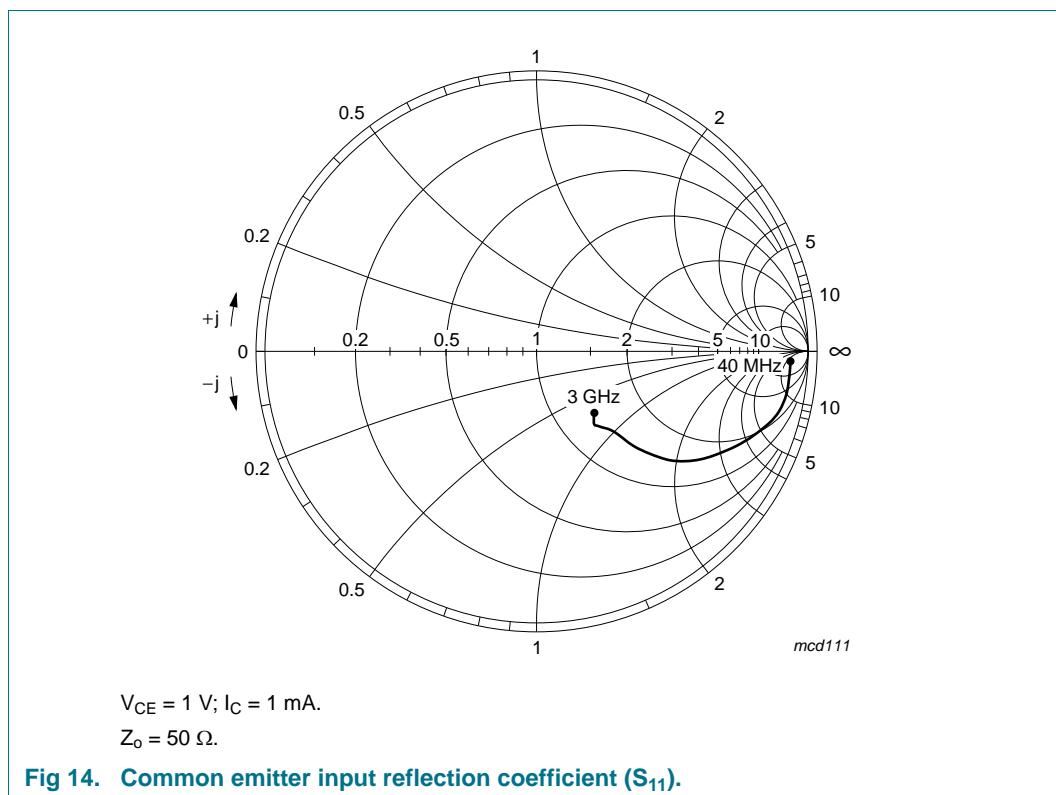


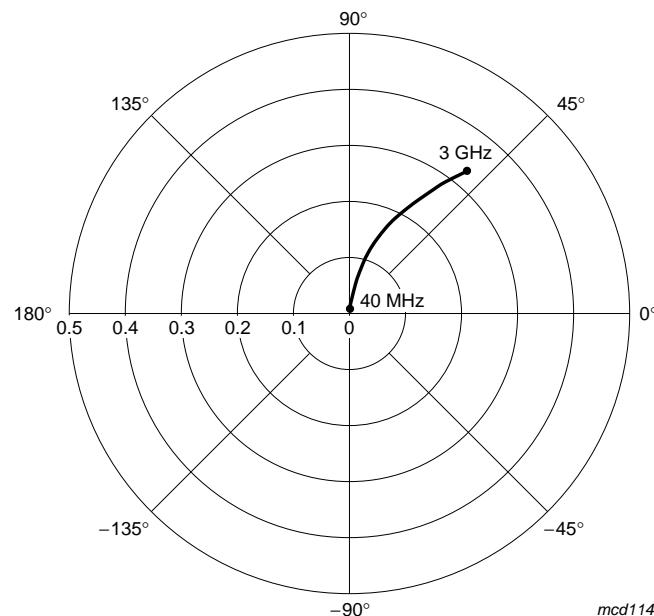
Table 9. Noise parameters

$f$ (MHz)	$V_{CE}$ (V)	$I_C$ (mA)	$F_{min}$ (dB)	$\Gamma_{opt}$ (mag)	$\Gamma_{opt}$ (ang)	$R_n/50$
1000	1	1	2	0.74	8	2.6

**Table 10. Noise parameters**

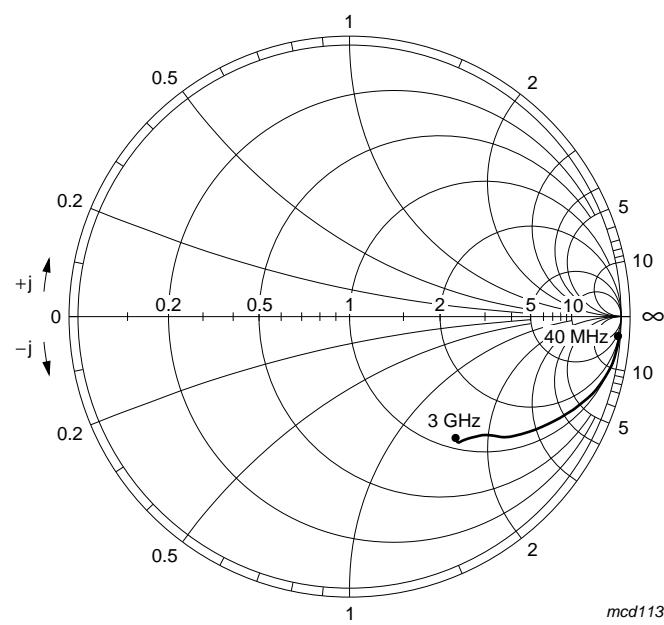
f (MHz)	V <sub>CE</sub> (V)	I <sub>C</sub> (mA)	F <sub>min</sub> (dB)	Γ <sub>opt</sub>		R <sub>n</sub> /50
				(mag)	(ang)	
2000	1	1	2.4	0.72	26	1.7





$V_{CE} = 1$  V;  $I_C = 1$  mA.

Fig 16. Common emitter reverse transmission coefficient ( $S_{12}$ ).



$V_{CE} = 1$  V;  $I_C = 1$  mA.

$Z_0 = 50 \Omega$ .

Fig 17. Common emitter output reflection coefficient ( $S_{22}$ ).

## 8. Package outline

Plastic surface-mounted package; 3 leads

SOT23

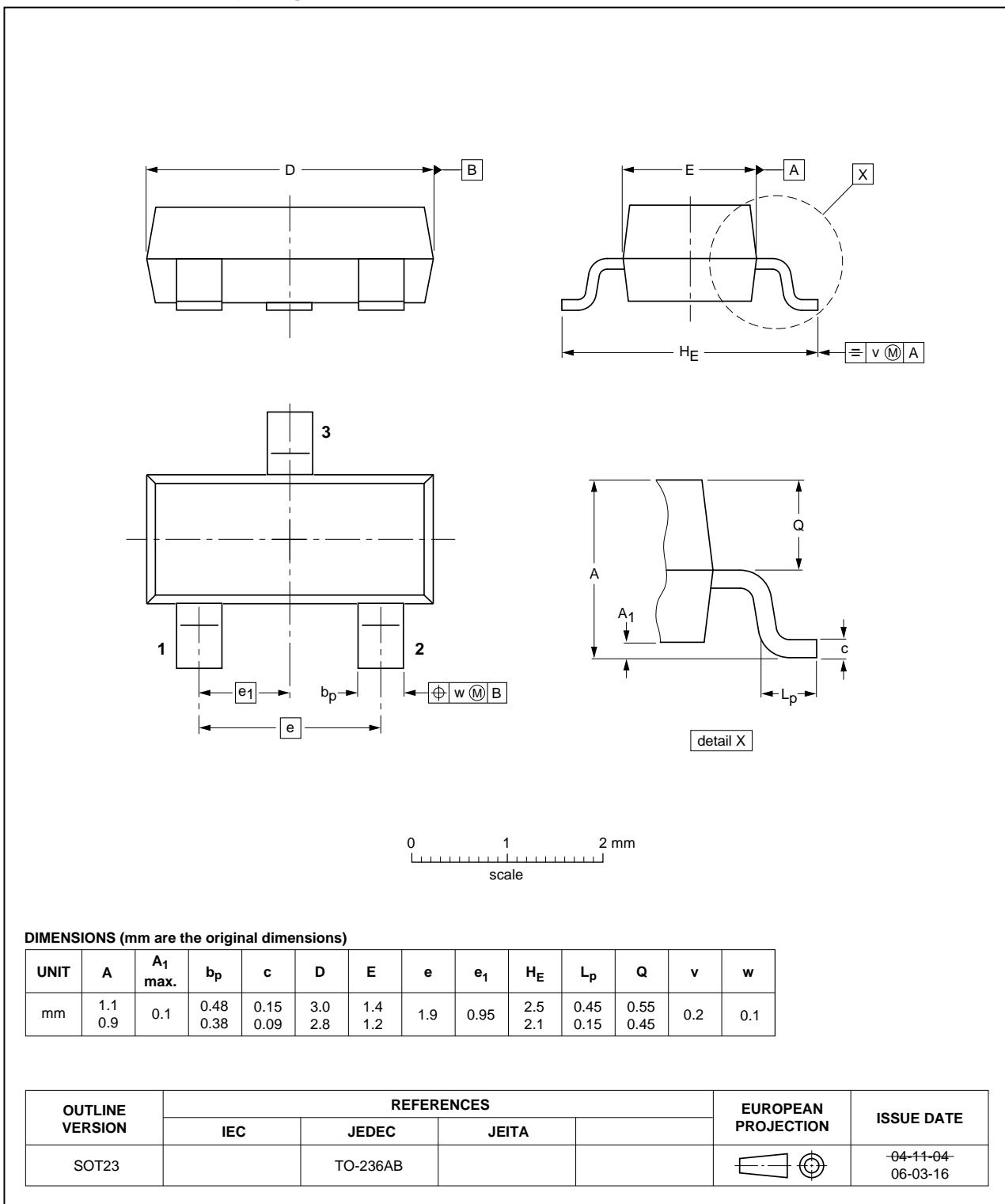


Fig 18. Package outline.

## 9. Revision history

**Table 11. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
BFT25A v.5	20110912	Product data sheet	-	BFT25A v.4
Modifications:	<ul style="list-style-type: none"><li>• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li><li>• Legal texts have been adapted to the new company name where appropriate.</li><li>• Package outline drawings have been updated to the latest version.</li></ul>			
BFT25A v.4 (9397 750 13399)	20040706	Product data sheet	-	BFT25A_CNV v.3
BFT25A_CNV v.3	19971205	Product specification	-	-

## 10. Legal information

### 10.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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